

RJH60M0DPQ-A0

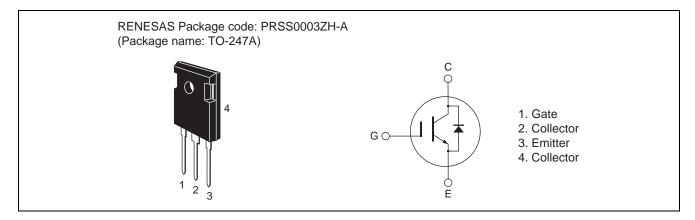
600 V - 22 A - IGBT Application: Inverter

R07DS0535EJ0100 Rev.1.00 Sep 02, 2011

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.8~V$ typ. (at $I_C=22~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 80 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 22 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	45	Α
	Tc = 100°C	Ic	22	Α
Collector peak current		ic(peak) Note1	90	Α
Collector to emitter diode forward current		I _{DF}	22	Α
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	90	Α
Collector dissipation		P _C Note2	140	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.89	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.3	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

RJH60M0DPQ-A0 **Preliminary**

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

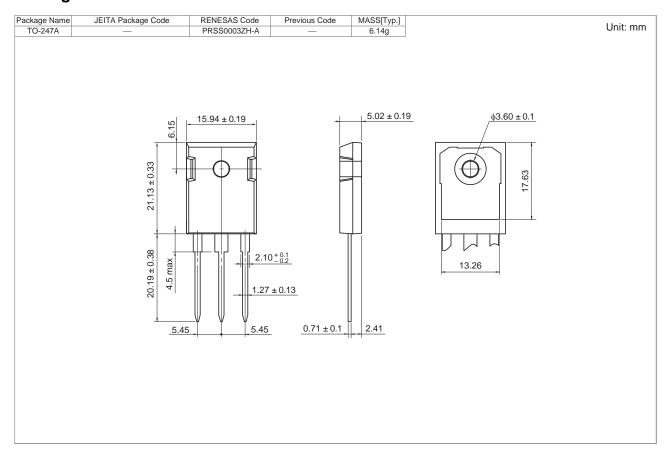
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	V _{CE} = 10 V, I _C = 1 mA	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	I _C = 22 A, V _{GE} = 15 V ^{Note3}	
	V _{CE(sat)}	_	2.2	_	V	$I_C = 45 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1050	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	70	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	32	_	pF	f = 1 MHz	
Total gate charge	Qg	_	45	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	6	_	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	20	_	nC	I _C = 22 A	
Switching time	t _{d(on)}	_	35	_	ns	$V_{CC} = 300 \text{ V}$, $V_{GE} = 15 \text{ V}$	
	t _r	_	20	_	ns	I _C = 22 A	
	t _{d(off)}	_	90	_	ns	$Rg = 5 \Omega$	
	t _f	_	80	_	ns	Inductive load	
Short circuit withstand time	t _{sc}	6	8	_	μS	Tc = 100 °C	
						$V_{CC} \leq 360~V$, V_{GE} = 15 V	
	1						
FRD Forward voltage	V_{F}	_	1.4	1.9	V	I _F = 22 A ^{Note3}	
FRD reverse recovery time	t _{er}	_	100	_	ns	I _E = 22 A	

FRD Forward voltage	V_{F}	_	1.4	1.9	V	$I_F = 22 A^{Note3}$
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 22 A
						$di_F/dt = 100 A/\mu s$

Notes: 3. Pulse test

RJH60M0DPQ-A0 Preliminary

Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M0DPQ-A0-T0	240 pcs	Box (Tube)

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +444-1628-585-100, Fax: +444-1628-585-900 Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-2353-1155, Fax: +86-10-8235-7679

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 161F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852-2886-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiv Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 1 harbourFront Avenue, #06-10, keppel Bay Tower, Singapore 098632 Tel: +65-6213-0200, Fax: +65-6278-8001

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

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